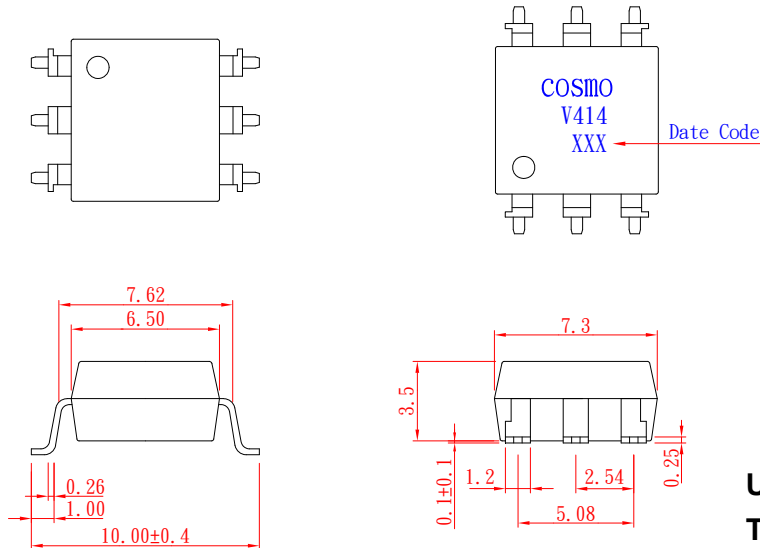


# PRODUCT SPECIFICATION

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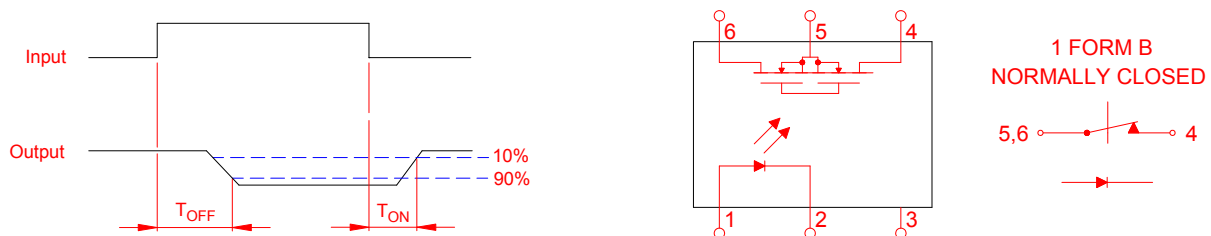
<b>cosmo</b> ELECTRONICS CORPORATION	SOLID STATE RELAY - MOSFET OUTPUT <b>KAQV414A</b>	NO.61M11006	REV. 2
		SHEET 1 OF 7	

## ● OUTSIDE DIMENSION :



Unit : mm  
Tolerance : ±0.2mm

## ● Operate / Reverse time



## ● Absolute Maximum Ratings

(Ta=25°C)

Emitter (Input)		Detector (Output)	
Reverse Voltage .....	5.0V	Output Breakdown Voltage .....	± 400V
Continuous Forward Current .....	50mA	Continuous Load Current .....	± 130mA
Peak Forward Current .....	1A	Power Dissipation .....	500mW
Power Dissipation .....	100mW		
Derate Linearly from 25°C .....	1.3mW/°C		
General Characteristics			
Isolation Test Voltage .....	3750VACrms	Storage Temperature Range .....	-40°C to +125°C
Isolation Resistance		Operating Temperature Range ...	-40°C to +85°C
Vio=500V , Ta=25°C .....	≥ 10 <sup>10</sup> Ω	Junction Temperature .....	100°C
Total Power Dissipation .....	550mW	Soldering Temperature ,	
Derate Linearly from 25°C .....	2.5mW/°C	2mm from case , 10 sec .....	260°C

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## ● Electro-optical Characteristics

(Ta=25°C)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit.	
Emitter ( Input )							
Forward Voltage	$V_F$	$I_F=10\text{mA}$		1.2	1.5	V	
Operation Input Current	$I_{F\text{OFF}}$	$V_L=\pm 20\text{V}$ , $I_L \leq 5\mu\text{A}$			5.0	mA	
Recovery Input Current	$I_{F\text{ON}}$	$V_L=\pm 20\text{V}$ , $I_L=100\text{mA}$ , $t=10\text{ms}$	0.2			mA	
Detector ( Output )							
Output Breakdown Voltage	$V_B$	$I_B=50\mu\text{A}$ , $I_F=10\text{mA}$	400			V	
Output Off-State Leakage	$I_{T\text{OFF}}$	$V_T=100\text{V}$ , $I_F=10\text{mA}$		0.2	2	$\mu\text{A}$	
I/O Capacitance	$C_{\text{ISO}}$	$I_F=0$ , $f=1\text{MHz}$		6		pF	
ON Resistance	Connection	A	$I_L=100\text{mA}$ , $I_F=0\text{mA}$		25	50	$\Omega$
		B			13	25	
		C			6	12.5	
Reverse ( ON ) Time	$T_{\text{ON}}$	$I_F=10\text{mA}$ , $V_L=\pm 20\text{V}$ $t=10\text{ms}$ , $I_L=\pm 100\text{mA}$		0.6	1.5	ms	
Operate ( OFF ) Time	$T_{\text{OFF}}$			0.3	1.0	ms	

## ● Schematic and Wiring Diagrams

Schematic	Output Configuration	Load	Connection	Wiring Diagrams
	1b	AC/DC	A	
		DC	B	
		DC	C	

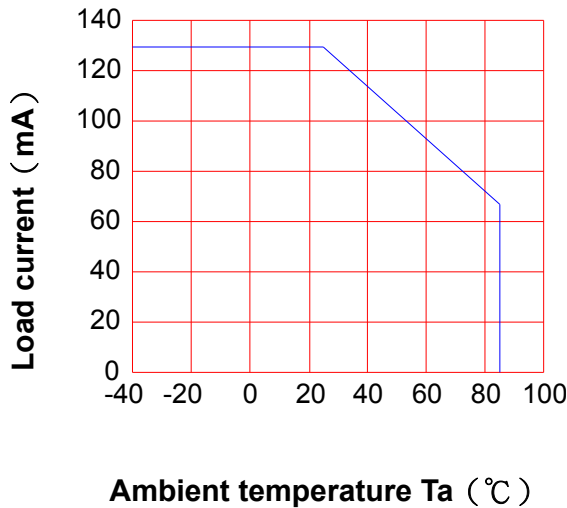
# PRODUCT SPECIFICATION

DATE : 02/22/2011

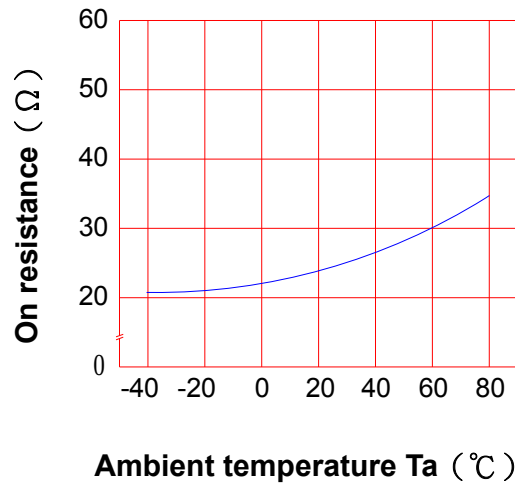
<b>cosmo</b> ELECTRONICS CORPORATION	SOLID STATE RELAY - MOSFET OUTPUT <b>KAQV414A</b>	NO.61M11006	REV. 2
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## ● Data Curve

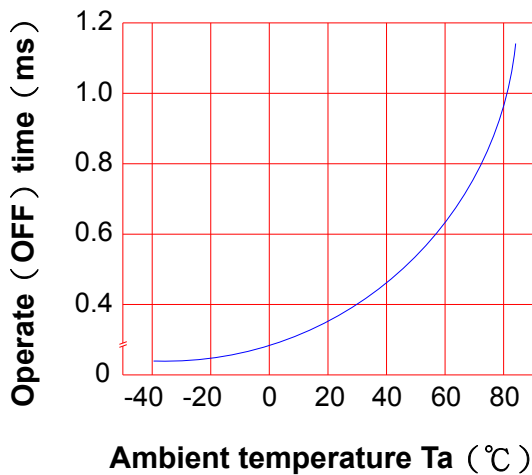
Load current vs. ambient temperature  
 Allowable ambient Temperature :  
 -40°C to +85°C



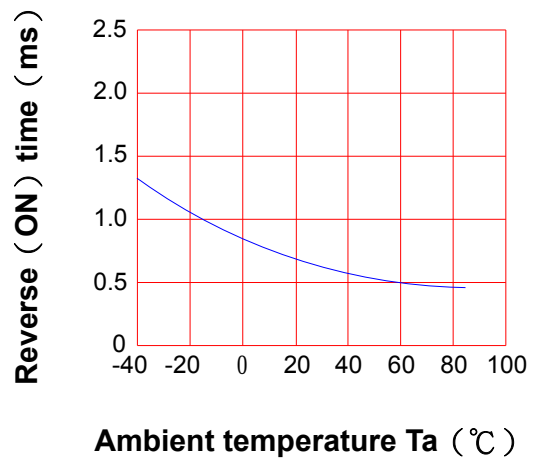
On resistance vs. ambient temperature  
 across terminals 4 and 6 pin  
 LED current : 5mA  
 Continuous load current : 130mA (DC)



Operate (OFF) time vs.  
 ambient temperature  
 Load voltage 400V (DC)  
 LED current : 5mA  
 Continuous load current : 130mA (DC)



Reverse (ON) time vs.  
 ambient temperature  
 Load voltage 400V (DC)  
 LED current : 5mA  
 Continuous load current : 130mA (DC)

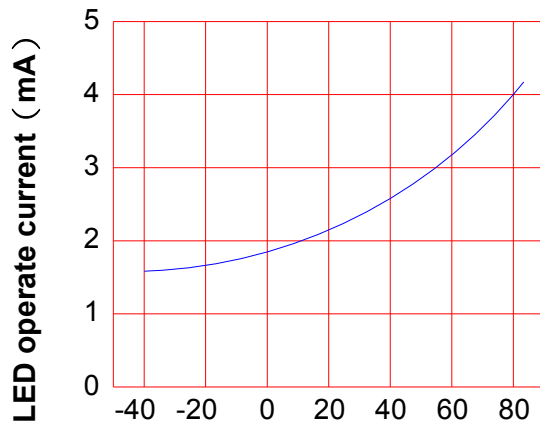


# PRODUCT SPECIFICATION

DATE : 02/22/2011

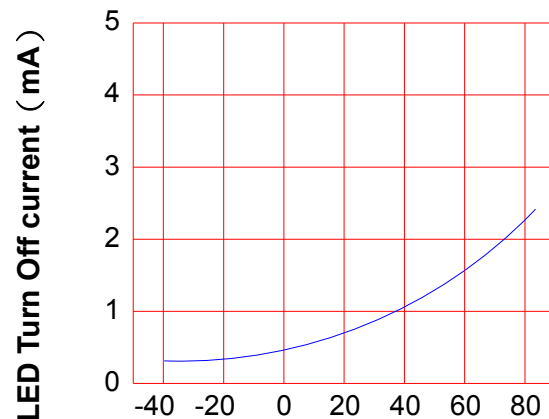
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LED operate current vs.  
ambient temperature  
Load Voltage : 400V (DC)  
Continuous load current : 130mA (DC)



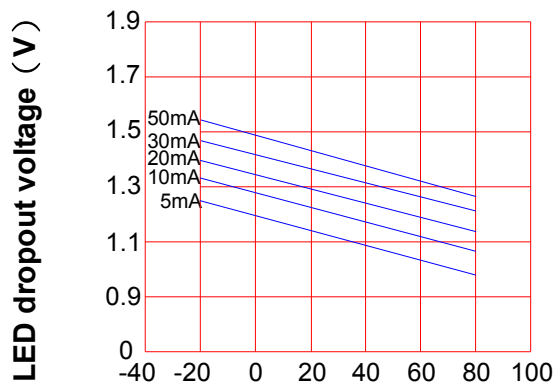
Ambient temperature Ta (°C)

LED Turn Off current vs.  
ambient temperature  
Load Voltage : 400V (DC)  
Continuous load current : 130mA (DC)



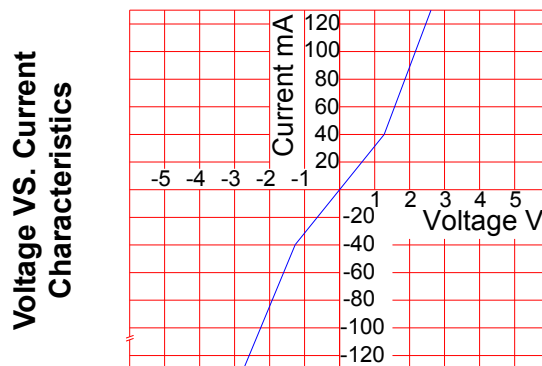
Ambient temperature Ta (°C)

LED dropout voltage vs.  
ambient temperature  
LED current : 5 to 50mA



Ambient temperature Ta (°C)

Voltage vs. current characteristics  
of output at MOSFET portion  
Measured portion : across terminals  
4 and 6 pin  
Ambient temperature : 25°C



Ambient temperature : 25°C

# PRODUCT SPECIFICATION

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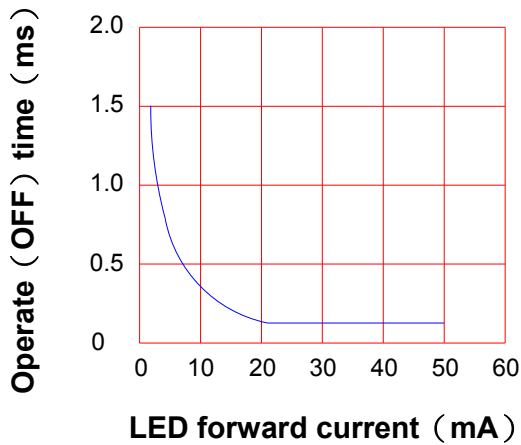
## LED forward current vs. Operate (OFF) time

Across terminals 4 and 6 pin

Load voltage : 400V (DC)

Continuous load current : 130mA (DC)

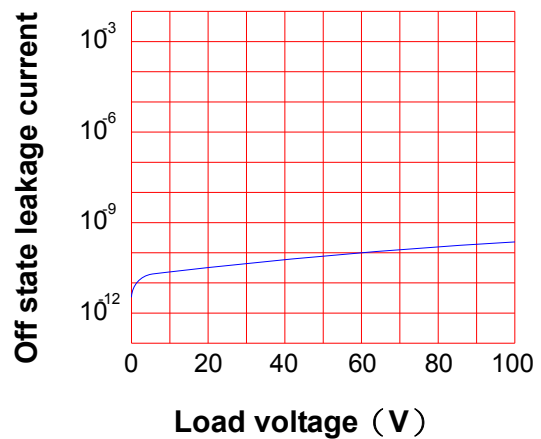
Ambient temperature : 25°C



## Off state leakage current

Across terminals 4 and 6 pin

Ambient temperature : 25°C



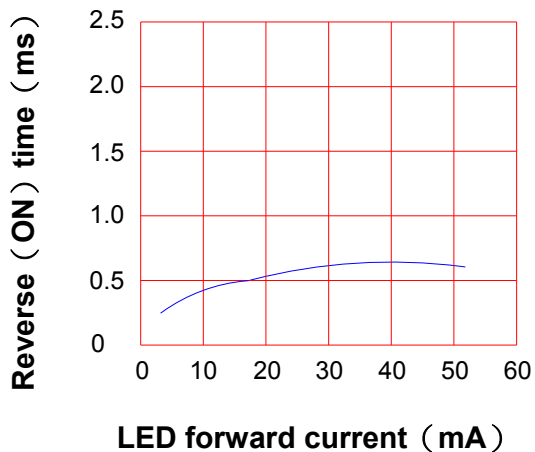
## LED forward current vs. reverse (ON) time

Across terminals 4 and 6 pin

Load voltage : 400V (DC)

Continuous load current : 130mA (DC)

Ambient temperature : 25°C

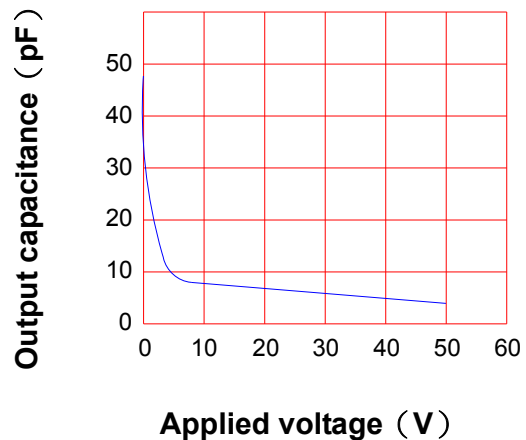


## Applied voltage vs. output capacitance

Across terminals 4 and 6 pin

Frequency : 1MHz

Ambient temperature : 25°C



# PRODUCT SPECIFICATION

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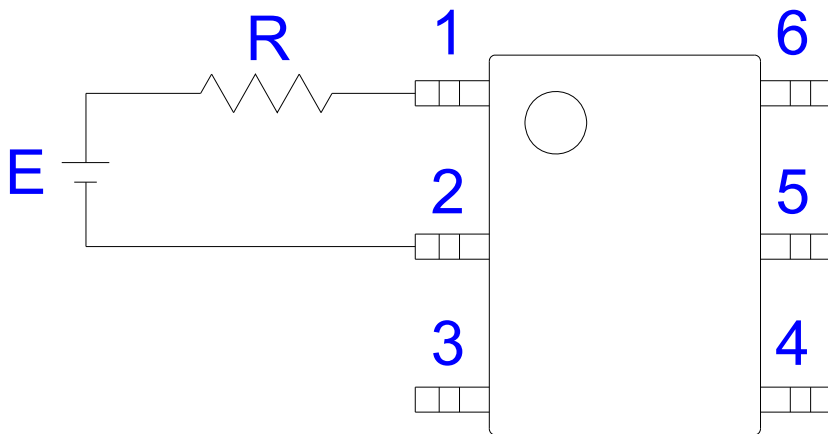
<b>cosmo</b> ELECTRONICS CORPORATION	SOLID STATE RELAY - MOSFET OUTPUT <b>KAQV414A</b>	NO.61M11006	REV. 2
		SHEET 6 OF 7	

## ● USING METHODS

Examples of resistance value to control LED forward current ( $I_F$ )

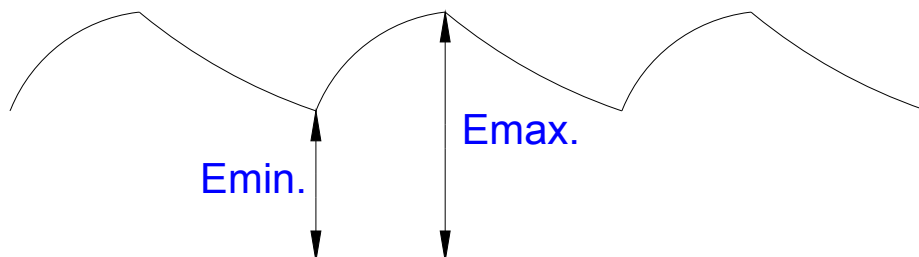
SSR-MOSFET OUTPUT

( $I_F=5\text{mA}$ )



E	R
3.3V	Approx. 330 $\Omega$
5V	Approx. 640 $\Omega$
12V	Approx. 1.9K $\Omega$
15V	Approx. 2.5K $\Omega$
24V	Approx. 4.1K $\Omega$

- (1) LED forward current must be more than 5mA , at E min.
- (2) LED forward current must be less than 50mA , at E max.



# PRODUCT SPECIFICATION

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ELECTRONICS CORPORATION

SOLID STATE RELAY - MOSFET OUTPUT  
**KAQV414A**

NO.61M11006  
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2

## ● USING METHODS

Regulate the spike voltage generated on the inductive load as follows :

